MSQ10HN03B

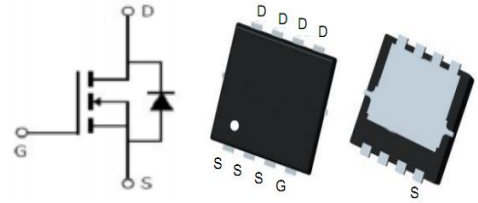
30V/100A N- Channel Advanced Power MOSFET

Features

- Low on-resistance and low conduction losses
- 100% Avalanche Tested

Applications

- High Side Load Switch
- Battery Switch
- Optimized for Power Management Applications for Portable Products, such as Aeromodelling, Power bank, Brushless motor, Main board and Others



PDFN3333

BVDSS	30	V
ID	100	A
RDSON@VGS=10V	3.1	mΩ
RDSON@VGS=4.5V	4.5	mΩ

Order Information

Product	Package	Marking	Reel Size	Reel	Carton
MSQ10HN03B	PDFN3333	PTQ10HN03	13inch	5000PCS	50000PCS

Absolute Maximum Ratings

Symbol	Parameter		Rating	Unit
Common Ratings (TC=25°C Unless Otherwise Noted)				
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage		30	V
V_{GS}	Gate-Source Voltage		±20	V
T_J	Maximum Junction Temperature		150	°C
T_{STG}	Storage Temperature Range		-55 to 150	°C
I_S	Diode Continuous Forward Current	TC =25°C	100	A
Mounted on Large Heat Sink				
E_{AS}	Single Pulse Avalanche Energy (Note1)		163	mJ
I_{DM}	Pulse Drain Current Tested (Note2)	TC =25°C	300	A
I_D	Continuous Drain current	TC =25°C	100	A
P_D	Maximum Power Dissipation	TC =25°C	54	W
$R_{\theta Jc}$	Thermal Resistance Junction−to−Case		2.31	°C/W

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
$V_{(BR)DSS}$	Drain- Source Breakdown Voltage	VGS=0V ID=250μA	30	--	--	V
I_{DSS}	Zero Gate Voltage Drain current	VDS=30V,VGS=0V	--	--	1	μA
I_{GSS}	Gate-Body Leakage Current	VGS=±20V,VDS=0V	--	--	±100	nA
$V_{GS(TH)}$	Gate Threshold Voltage	VDS=VGS,ID=250μA	1	--	2.5	V
$R_{DS(ON)}$	Drain-Source On-State Resistance (Note3)	VGS=10V, ID=20A	--	3.1	4	mΩ
		VGS=4.5V, ID=15A	--	4.5	6	
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated) (Note4)						
C_{iss}	Input Capacitance	VDS=15V, VGS=0V, F=1MHz	--	2930	--	pF
C_{oss}	Output Capacitance		--	300	--	pF
C_{rss}	Reverse Transfer Capacitance		--	278	--	pF
Q_g	Total Gate Charge	VDS=15V, ID=20A, VGS=10V	--	55	--	nC
Q_{gs}	Gate-Source Charge		--	11	--	nC
Q_{gd}	Gate-Drain Charge		--	9	--	nC
Switching Characteristics (Note4)						
$t_{d(on)}$	Turn-on Delay Time	VDD=15V, ID=20A, VGS=10V RG=3Ω	--	7.8	--	nS
t_r	Turn-on Rise Time		--	11	--	nS
$t_{d(off)}$	Turn-off Delay Time		--	65	--	nS
t_f	Turn-off Fall Time		--	22	--	nS
Source- Drain Diode Characteristics@ TJ = 25°C (unless otherwise stated)						
V_{SD}	Forward on voltage	IS=20A,VGS=0V	--	--	1.2	V

Note:

1. Limited by TJmax, starting TJ = 25° C, RG = 25Ω, VD =15V, VGS =10V. Part not recommended for use above this value.
2. Repetitive Rating: Pulse width limited by maximum junction temperature.
3. Pulse Test: pulse width ≤ 300 us, duty cycle ≤ 2%.
4. Guranteed by design, not subject to production testing.

Typical Characteristics

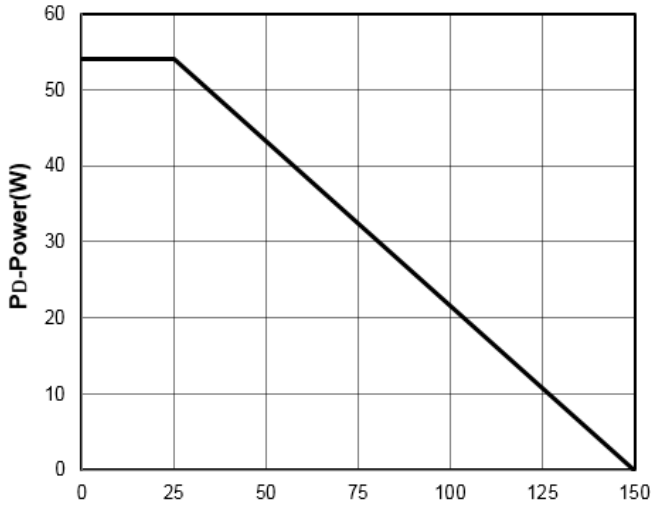


Figure1：T_J Junction Temperature（°C）

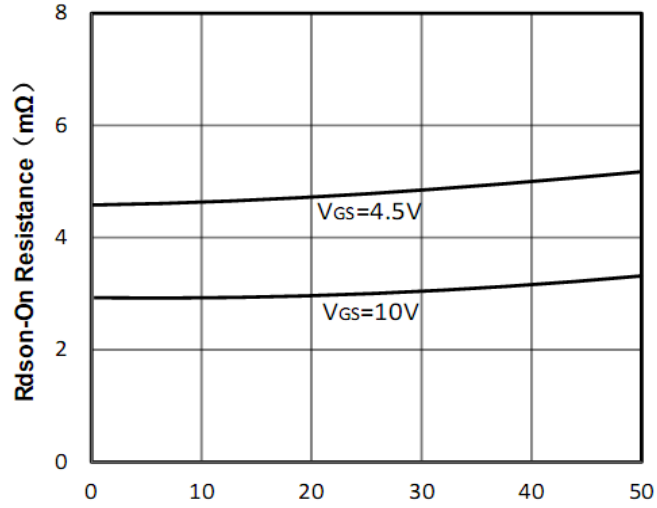


Figure2：I_D Drain Current（A）

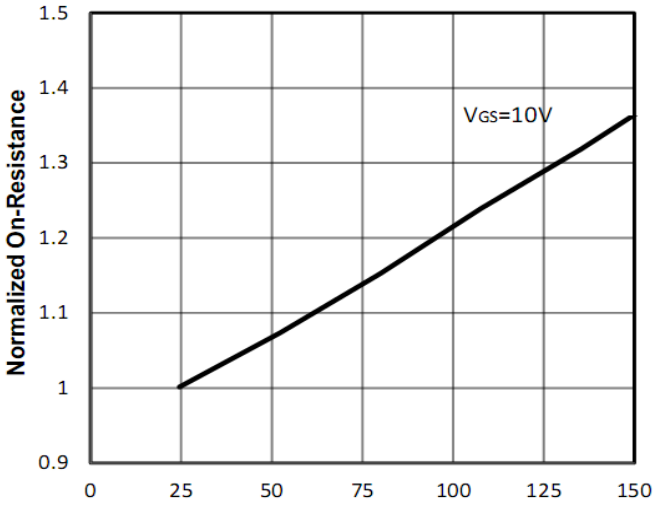


Figure3：T_J Junction Temperature（°C）

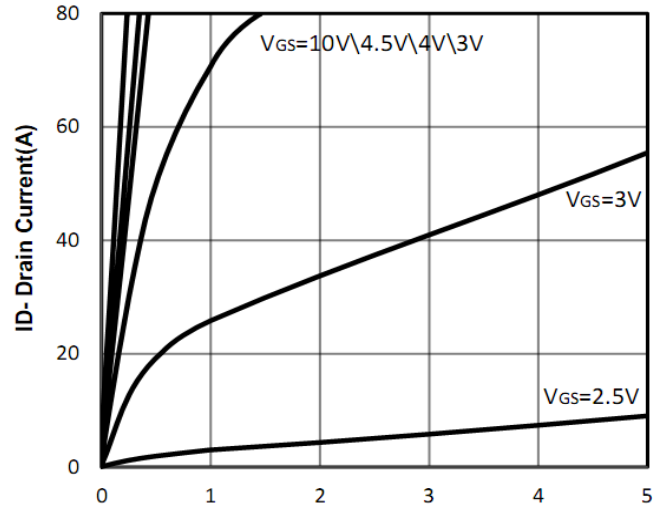


Figure4：V_{DS} Drain-Source Voltage（V）

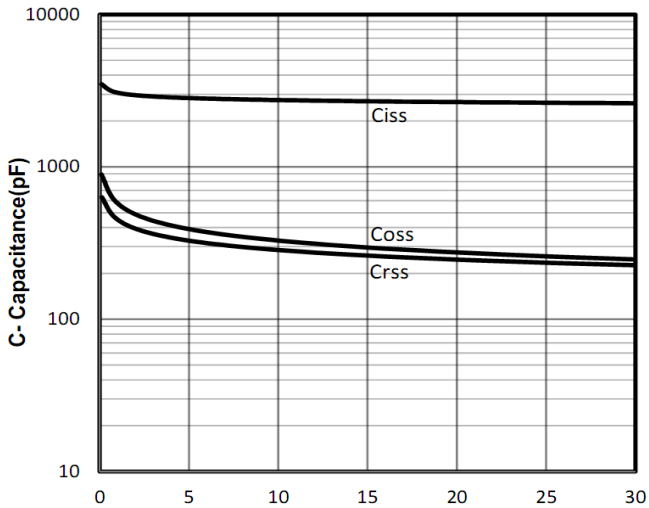


Figure5：V_{DS} Drain-Source Voltage（V）

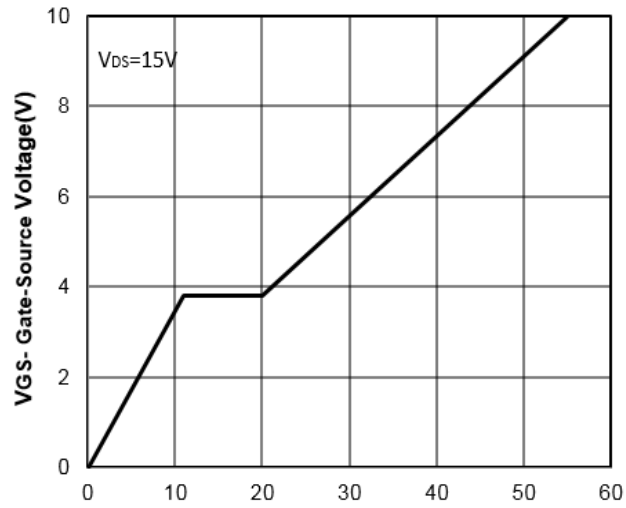


Figure6：Qg Gate Charge（nC）

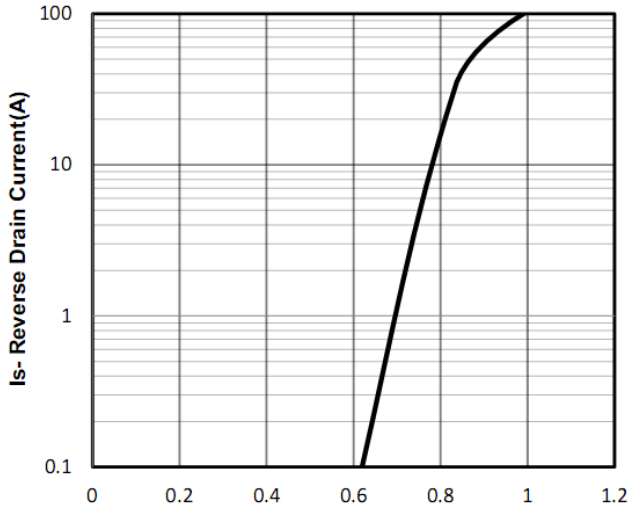


Figure7：Vsd Source-Drain Voltage（V）

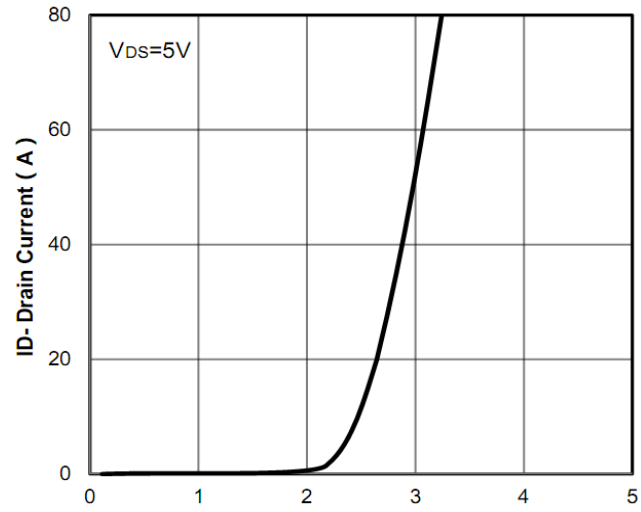


Figure8：Vgs Gate-Source Voltage（V）

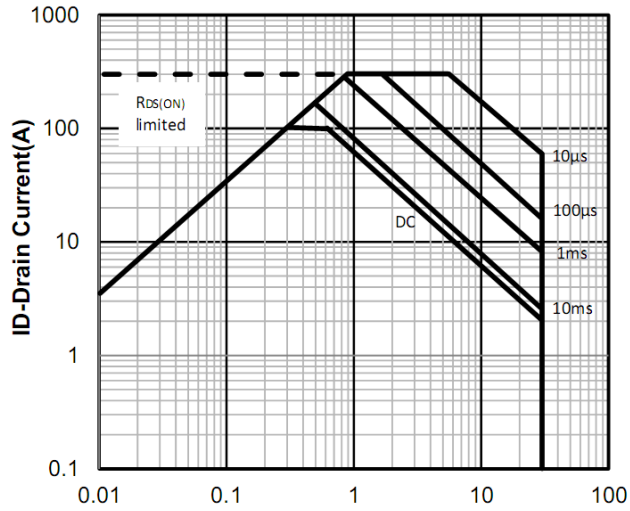


Figure9：VDS Drain -Source Voltage（V）

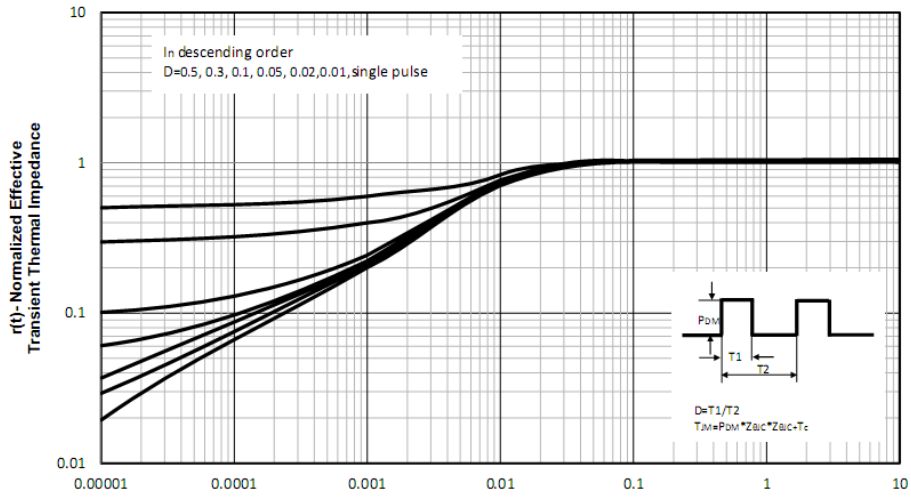


Figure10：Square Wave Pulse Duration（sec）

Test Circuit and Waveform:

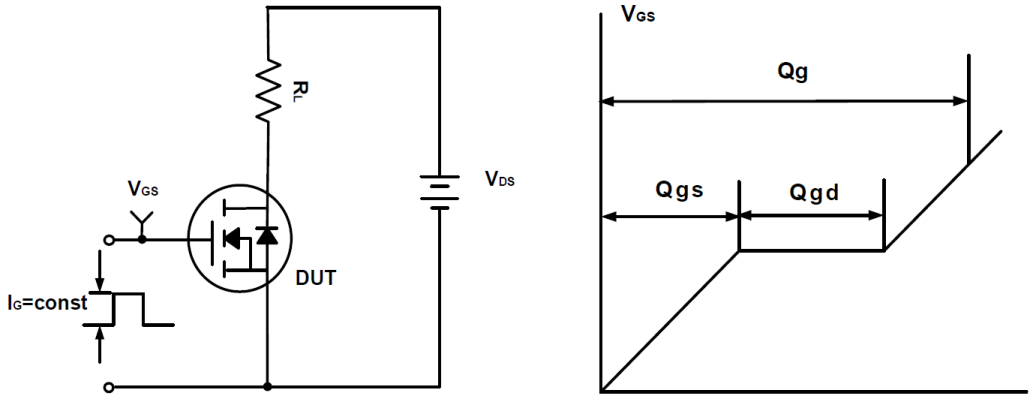


Figure A Gate Charge Test Circuit &Waveforms

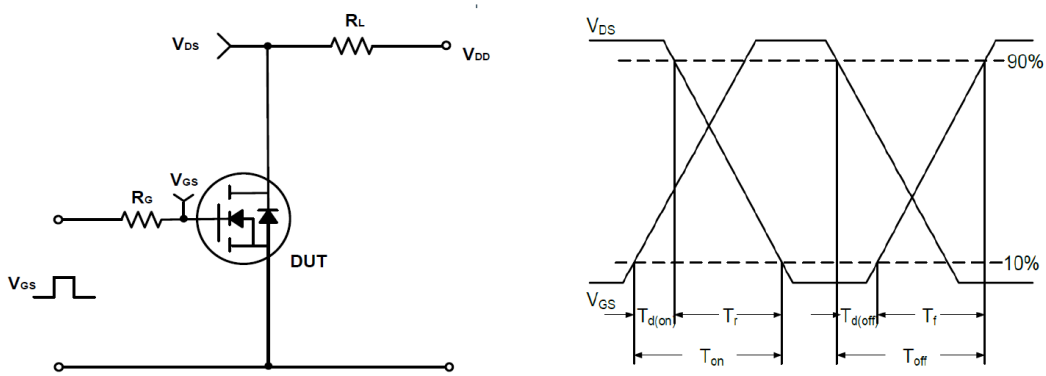


Figure B Switching Test Circuit & Waveforms

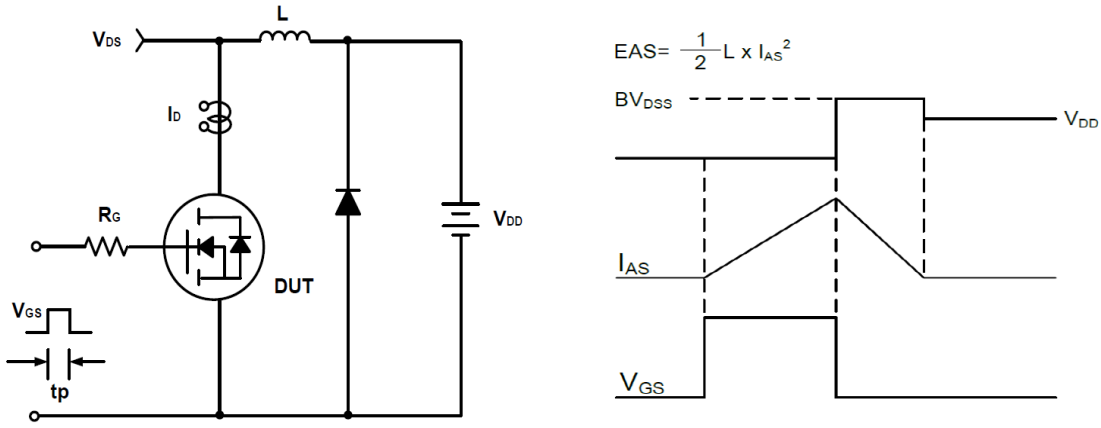
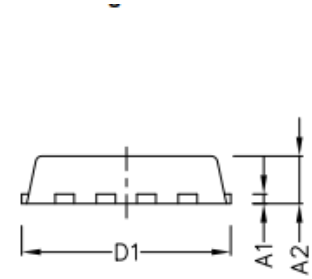
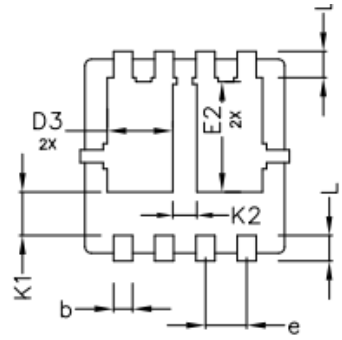


Figure C Unclamped Inductive Switching Circuit & Waveforms

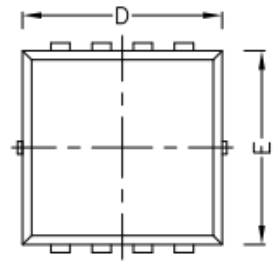
PDFN3333 Package Outline Dimensions (Units: mm)



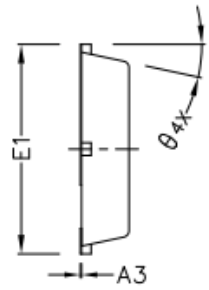
SIDE VIEW



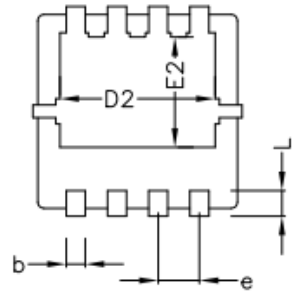
BOTTOM VIEW
OPTION 2



TOP VIEW



SIDE VIEW



BOTTOM VIEW
OPTION 1

COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A1		0.152 BSC	
A2	0.650	0.750	0.850
A3	0.005	–	0.020
b	0.250	0.300	0.350
D	3.050	3.150	3.250
D1	3.200	3.300	3.400
D2	2.350	2.450	2.550
D3	0.935	1.035	1.135
E1	3.150	3.300	3.450
E	2.950	3.050	3.150
E2	1.635	1.735	1.835
e		0.650 TYPE	
L	0.300	0.400	0.500
θ		12° TYPE	
K1		0.680 REF	
K2		0.380 REF	
L1		0.410 REF	